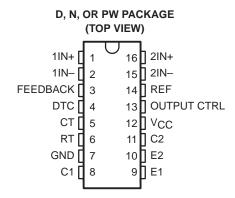
- Complete PWM Power Control Circuitry
- Uncommitted Outputs for 200-mA Sink or Source Current
- Output Control Selects Single-Ended or Push-Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Variable Dead Time Provides Control Over Total Range
- Internal Regulator Provides a Stable 5-V Reference Supply Trimmed to 1%
- Circuit Architecture Allows Easy Synchronization
- Undervoltage Lockout for Low V<sub>CC</sub>
   Conditions



## description

The TL594 incorporates all the functions required in the construction of a pulse-width-modulation (PWM) control circuit on a single chip. Designed primarily for power-supply control, these devices offer the systems engineer the flexibility to tailor the power-supply control circuitry to a specific application.

The TL594 contains two error amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, a 5-V regulator with a precision of 1%, an undervoltage lockout control circuit, and output control circuitry.

The error amplifiers exhibit a common-mode voltage range from -0.3 V to  $V_{CC}$  -2 V. The DTC comparator has a fixed offset that provides approximately 5% dead time. The on-chip oscillator can be bypassed by terminating RT to the reference output and providing a sawtooth input to CT, or it can be used to drive the common circuitry in synchronous multiple-rail power supplies.

The uncommitted output transistors provide either common-emitter or emitter-follower output capability. Each device provides for push-pull or single-ended output operation, with selection by means of the output-control function. The architecture of these devices prohibits the possibility of either output being pulsed twice during push-pull operation. The undervoltage lockout control circuit locks the outputs off until the internal circuitry is operational.

The TL594C is characterized for operation from 0°C to 70°C. The TL594I is characterized for operation from –40°C to 85°C.

#### **FUNCTION TABLE**

INPUT	OUTPUT FUNCTION  Single-ended or parallel output	
OUTPUT CTRL	OUTPUT FUNCTION	
V <sub>I</sub> = -0	Single-ended or parallel output	
V <sub>I</sub> = V <sub>ref</sub>	Normal push-pull operation	



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

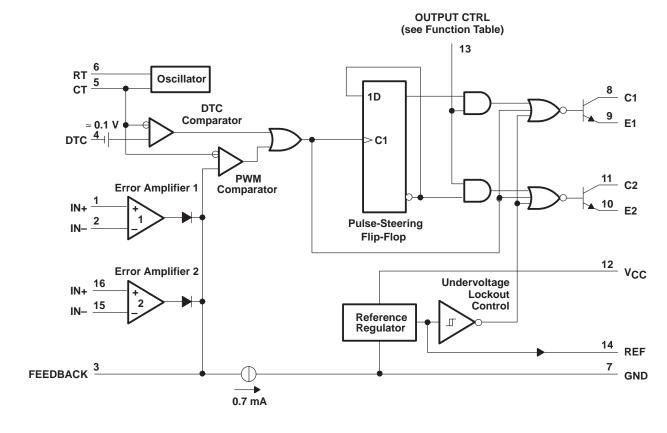


#### **AVAILABLE OPTIONS**

	PA	CKAGED DEVICES	5	
TA	SMALL OUTLINE (D)	PLASTIC DIP (N)	PLASTIC THIN SHRINK SMALL OUTLINE (PW)	CHIP FORM (Y)
0°C to 70°C	TL594CD	TL594CN	TL594CPW	TL594Y
-40°C to 85°C	TL594ID	TL594IN	TL594IPW	115941

The D and PW packages are also available taped and reeled. Add the suffix R to device type (e.g., TL594CDR). Chip forms are tested at 25°C.

### functional block diagram





## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1)		
Amplifier input voltage		
Collector output voltage		41 V
Collector output current		250 mA
Package thermal impedance, θ <sub>JA</sub> (see Note	2): D package	
	N package	67°C/W
	PW package	108°C/W
Lead temperature 1,6 mm (1/16 inch) from o	case for 10 seconds	260°C
Storage temperature range, T <sub>stq</sub>		

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The package thermal impedance is calculated in accordance with JESD 51.

#### recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V <sub>CC</sub>		7	40	V
Amplifier input voltage, V <sub>I</sub>		-0.3	V <sub>CC</sub> -2	V
Collector output voltage, VO			40	V
Collector output current (each transistor)				mA
Current into feedback terminal				mA
Timing capacitor, C <sub>T</sub>		0.47	10000	nF
Timing resistor, R <sub>T</sub>		1.8	500	kΩ
Oscillator frequency, fosc			300	kHz
One wating free air temperature T.	TL594C	0	70	°C
Operating free-air temperature, T <sub>A</sub>	TL594I	-40	85	°C

NOTES: 1. All voltage values, except differential voltages, are with respect to the network ground terminal.

# electrical characteristics over recommended operating conditions, $V_{CC} = 15 \text{ V}$ , (unless otherwise noted)

#### reference section

PARAMETER	TEGT 0011DI	TL594C, TL594I			UNIT	
PARAMETER	TEST CONDIT	TEST CONDITIONS†		TYP <sup>‡</sup>	MAX	UNIT
Output voltage (REF)	I <sub>O</sub> = 1 mA,	T <sub>A</sub> = 25°C	4.95	5	5.05	V
Input regulation	$V_{CC} = 7 \text{ V to } 40 \text{ V},$	T <sub>A</sub> = 25°C		2	25	mV
Output regulation	$I_0 = 1$ to 10 mA,	T <sub>A</sub> = 25°C		14	35	mV
Output-voltage change with temperature	$\Delta T_A = MIN \text{ to MAX}$			2	10	mV/V
Short-circuit output current§	$V_{ref} = 0$		10	35	50	mA

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

#### amplifier section (see Figure 1)

DADAMETER	TEST COMPITIONS		TL594C, TL594I			шыт	
PARAMETER	16	TEST CONDITIONS		MIN	TYP‡	MAX	UNIT
Input offset voltage, error amplifier	FEEDBACK = 2.5 V				2	10	mV
Input offset current	FEEDBACK = 2.5 V				25	250	nA
Input bias current	FEEDBACK = 2.5 V				0.2	1	μΑ
Common-mode input voltage range, error amplifier	V <sub>CC</sub> = 7 V to 40 V			0.3 to VCC-	-2		V
Open-loop voltage amplification, error amplifier	$\Delta V_{O} = 3 V$ ,	$R_L = 2 k\Omega$ ,	$V_0 = 0.5 \text{ V to } 3.5 \text{ V}$	70	95		dB
Unity-gain bandwidth	$V_0 = 0.5 \text{ V to } 3.5 \text{ V},$	$R_L = 2 k\Omega$			800		kHz
Common-mode rejection ratio, error amplifier	V <sub>CC</sub> = 40 V,	T <sub>A</sub> = 25°C		65	80	·	dB
Output sink current, FEEDBACK	$V_{ID} = -15 \text{ mV to } -5 \text{ V},$	FEEDBACK =	0.5 V	0.3	0.7		mA
Output source current, FEEDBACK	$V_{ID}$ = 15 mV to 5 V,	FEEDBACK =	3.5 V	-2			mA

<sup>‡</sup> All typical values except for parameter changes with temperature are at T<sub>A</sub> = 25°C.

#### oscillator section, $C_T$ = 0.01 $\mu$ F, $R_T$ = 12 $k\Omega$ (see Figure 2)

PARAMETER		TL59	UNIT		
PARAMETER	TEST CONDITIONS†	MIN	TYP‡	MAX	ONII
Frequency			10		kHz
Standard deviation of frequency¶	All values of V <sub>CC</sub> , C <sub>T</sub> , R <sub>T</sub> , and T <sub>A</sub> constant		100		Hz/kHz
Frequency change with voltage	$V_{CC} = 7 \text{ V to } 40 \text{ V},  T_A = 25^{\circ}\text{C}$		1		Hz/kHz
Frequency change with temperature#	$\Delta T_A = MIN \text{ to MAX}$			50	Hz/kHz

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

$$\sigma \ = \ \sqrt{\frac{\sum\limits_{n=1}^{N}(x_n-\overline{x})^2}{N-1}}$$



<sup>‡</sup> All typical values except for parameter changes with temperature are at  $T_A = 25$ °C.

<sup>§</sup> Duration of the short circuit should not exceed one second.

 $<sup>\</sup>frac{1}{2}$  All typical values except for parameter changes with temperature are at  $T_A = 25$ °C.

 $<sup>\</sup>P$  Standard deviation is a measure of the statistical distribution about the mean as derived from the formula:

<sup>#</sup> Temperature coefficient of timing capacitor and timing resistor not taken into account.

# electrical characteristics over recommended operating free-air temperature range, $V_{CC}$ = 15 V, (unless otherwise noted)

#### dead-time control section (see Figure 2)

PARAMETER	TEST CONDITIONS	TL59	UNIT		
PARAMETER	TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNII
Input bias current	V <sub>I</sub> = 0 to 5.25 V		-2	-10	μΑ
Maximum duty cycle, each output	DTC = 0 V	0.45			
Input throubold voltage	Zero duty cycle		3	3.3	\/
Input threshold voltage	Maximum duty cycle	0			V

 $<sup>\</sup>dagger$  All typical values except for parameter changes with temperature are at  $T_A = 25^{\circ}C$ .

#### output section

PARAMETER		TEST CONDITIONS		TL594C, TL594I			UNIT
PARAMETER		TEST CONDITIONS		MIN	TYP <sup>†</sup>	MAX	UNIT
Collector off-state current		$V_C = 40 \text{ V}, V_E = 0 \text{ V},$	V <sub>CC</sub> = 40 V		2	100	
		DTC and OUTPUT CT $V_C = 15 \text{ V},  V_E = 0$			4	200	μΑ
Emitter off-state current	Emitter off-state current $V_{CC} = V_C = 40 \text{ V},  V_E = 0$		VE = 0			-100	μΑ
Collector-emitter saturation voltage	Common emitter	VE = 0,	I <sub>C</sub> = 200 mA		1.1	1.3	V
Collector-entitler saturation voltage	Emitter follower	$V_C = 15 V$ ,	I <sub>E</sub> = −200 mA		1.5	2.5	V
Output control input current		$V_I = V_{ref}$				3.5	mA

 $<sup>\</sup>overline{}^{\dagger}$  All typical values except for parameter changes with temperature are at T<sub>A</sub> = 25°C.

#### pwm comparator section (see Figure 2)

PARAMETER	TEST CONDITIONS	TL594C, TL594I			LINUT
PARAMETER	TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
Input threshold voltage, FEEDBACK	Zero duty cycle		4	4.5	V
Input sink current, FEEDBACK	FEEDBACK = 0.5 V	0.3	0.7		mA

 $<sup>^\</sup>dagger$  All typical values except for parameter changes with temperature are at  $T_A = 25$ °C.

#### undervoltage lockout section (see Figure 2)

PARAMETER	TEST SOMBITIONS!	TL594C,	UNIT	
PARAMETER	TEST CONDITIONS‡	MIN	MAX	UNIT
Threshold voltage	T <sub>A</sub> = 25°C		6	V
	$\Delta T_A = MIN \text{ to MAX}$	3.5	6.9	V
Hysteresis§		100		mV

<sup>‡</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

<sup>\$</sup> Hysteresis is the difference between the positive-going input threshold voltage and the negative-going input threshold voltage.

PARAMETER	TEST CONDITIONS			TL594C, TL594I		
PARAMETER				TYP <sup>†</sup>	MAX	UNIT
Standby aupply aurrent	RT at V <sub>ref</sub> ,	V <sub>CC</sub> = 15 V		9	15	mA
Standby supply current	All other inputs and outputs open	V <sub>CC</sub> = 40 V		11	18	IIIA
Average supply current	DTC = 2 V,	See Figure 2		12.4		mA

 $<sup>^\</sup>dagger$  All typical values except for parameter changes with temperature are at  $T_A$  = 25°C.



electrical characteristics over recommended operating free-air temperature range,  $V_{CC} = 15 \text{ V}$ , (unless otherwise noted) (continued)

## switching characteristics, T<sub>A</sub> = 25°C

PARAMETER	TEST CONDITIONS  Common-emitter configuration (see Figure 3  Emitter-follower configuration (see Figure 4)		TL594C, TL594I			
PARAMETER			TYP <sup>†</sup>	MAX	UNIT	
Output-voltage rise time			100	200	ns	
Output-voltage fall time			30	100	ns	
Output-voltage rise time			200	400	ns	
Output-voltage fall time			45	100	ns	

<sup>†</sup> All typical values except for parameter changes with temperature are at T<sub>A</sub> = 25°C.

# electrical characteristics over recommended operating conditions, $V_{CC}$ = 15 V, $T_A$ = 25°C (unless otherwise noted)

#### reference section

PARAMETER	TEST CONDITIONS	7	UNIT		
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNII
Output voltage (REF)	I <sub>O</sub> = 1 mA		5		V
Input regulation	V <sub>CC</sub> = 7 V to 40 V		2		mV
Output regulation	I <sub>O</sub> = 1 to 10 mA		14		mV
Short-circuit output current‡	V <sub>ref</sub> = 0		35		mA

<sup>‡</sup> Duration of the short circuit should not exceed one second.

#### oscillator section, C<sub>T</sub> = 0.01 $\mu$ F, R<sub>T</sub> = 12 k $\Omega$ (see Figure 2)

PARAMETER	TEST CONDITIONS	TL594Y			UNIT
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Frequency			10		kHz
Standard deviation of frequency§	All values of $V_{CC}$ , $C_T$ , $R_T$ , and $T_A$ constant		100		Hz/kHz
Frequency change with voltage	V <sub>CC</sub> = 7 V to 40 V		1		Hz/kHz

<sup>§</sup> Standard deviation is a measure of the statistical distribution about the mean as derived from the formula:

$$\sigma = \sqrt{\frac{\sum_{n=1}^{N} (x_n - \overline{X})^2}{N-1}}$$

#### amplifier section (see Figure 1)

PARAMETER	TEST CONDITIONS		TL594Y			UNIT	
PARAMETER	15	51 CONDITIONS		MIN	TYP	MAX	UNIT
Input offset voltage, error amplifier	FEEDBACK = 2.5 V				2		mV
Input offset current	FEEDBACK = 2.5 V				25		nA
Input bias current	FEEDBACK = 2.5 V				0.2		μА
Open-loop voltage amplification, error amplifier	$\Delta V_{O} = 3 V$ ,	$R_L = 2 k\Omega$ , $V_O = 0.5 V t$	to 3.5 V		95		dB
Unity-gain bandwidth	$V_O = 0.5 \text{ V to } 3.5 \text{ V},$	R <sub>L</sub> = 2 kΩ			800		kHz
Common-mode rejection ratio, error amplifier	V <sub>CC</sub> = 40 V,	T <sub>A</sub> = 25°C			80	·	dB
Output sink current, FEEDBACK	$V_{ID} = -15 \text{ mV to } -5 \text{ V},$	FEEDBACK = 0.5 V			0.7		mA



# electrical characteristics over recommended operating free-air temperature range, $V_{CC}$ = 15 V, $T_A$ = 25°C (unless otherwise noted)

#### dead-time control section (see Figure 2)

PARAMETER	TEST CONDITIONS	٦	UNIT		
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNII
Input bias current	V <sub>I</sub> = 0 to 5.25 V		-2		μΑ
Input threshold voltage	Zero duty cycle		3		V

#### output section

PARAMETER		TEST CONDITIONS		TL594Y			UNIT
				MIN	TYP	MAX	UNIT
		$V_C = 40 \text{ V}, V_E = 0 \text{ V},$	$V_{CC} = 40 \text{ V}$		2		
Collector off-state current		DTC and OUTPUT CT $V_C = 15 \text{ V},  V_E = 0$			4		μΑ
Emitter off-state current		$V_{CC} = V_{C} = 40 \text{ V},$	VE = 0				μΑ
Collector-emitter saturation voltage	Common emitter	V <sub>E</sub> = 0,	$I_C = 200 \text{ mA}$		1.1		V
Collector-entitler saturation voltage	Emitter follower	$V_C = 15 V$ ,	$I_E = -200 \text{ mA}$		1.5		V

#### pwm comparator section (see Figure 2)

PARAMETER	TEST CONDITIONS	٦	LINUT		
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input threshold voltage, FEEDBACK	Zero duty cycle		4		V
Input sink current, FEEDBACK	FEEDBACK = 0.5 V		0.7		mA

#### total device (see Figure 2)

PARAMETER	TEST CONDITIONS			TL594Y			
PARAMETER	lesi conditi	ION3	MIN	TYP	MAX	UNIT	
Standby supply current	All other inputs and outputs open,	R <sub>T</sub> at V <sub>ref</sub>		9		mA	
Average supply current	DTC = 2 V,	See Figure 2		12.4		mA	

## switching characteristics, $T_A = 25^{\circ}C$

PARAMETER	TEST CONDITIONS  Common-emitter configuration (see Figure 3)  Emitter-follower configuration (see Figure 4)		TL594Y		
PARAMETER			TYP	MAX	UNIT
Output-voltage rise time			100		ns
Output-voltage fall time			30		ns
Output-voltage rise time			200		ns
Output-voltage fall time			45		ns

#### PARAMETER MEASUREMENT INFORMATION

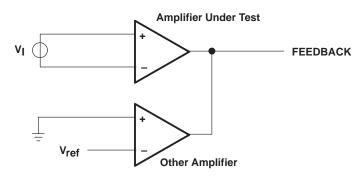
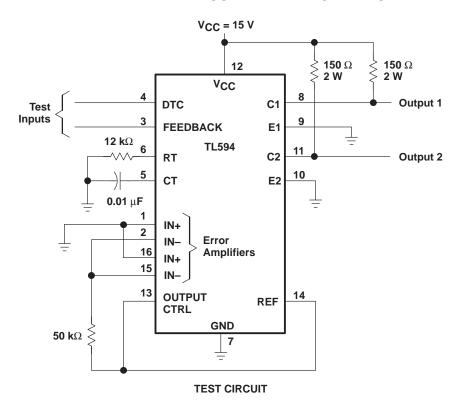


Figure 1. Amplifier-Characteristics Test Circuit



#### PARAMETER MEASUREMENT INFORMATION



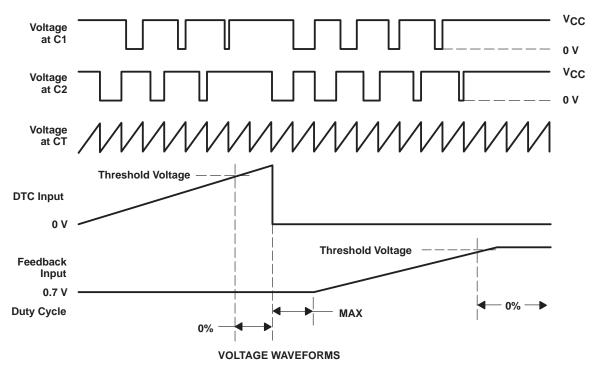


Figure 2. Operational Test Circuit and Waveforms



#### PARAMETER MEASUREMENT INFORMATION

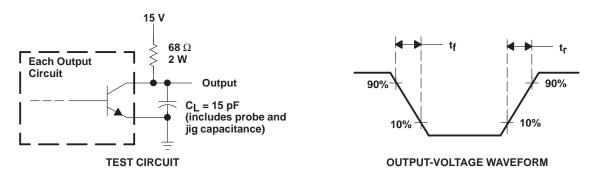


Figure 3. Common-Emitter Configuration

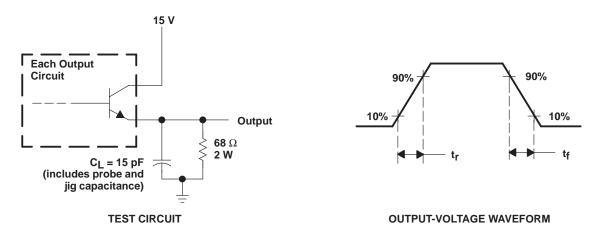
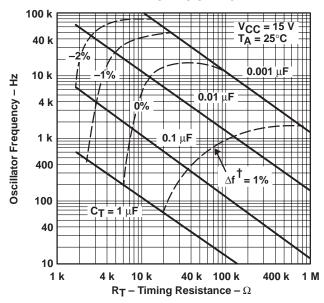


Figure 4. Emitter-Follower Configuration

#### **TYPICAL CHARACTERISTICS**

# OSCILLATOR FREQUENCY AND FREQUENCY VARIATION †

## TIMING RESISTANCE



<sup>†</sup> Frequency variation (Δf) is the change in oscillator frequency that occurs over the full temperature range.

Figure 5

# AMPLIFIER VOLTAGE AMPLIFICATION vs FREQUENCY

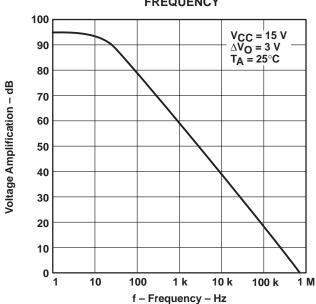


Figure 6



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